



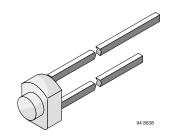
GaAs Infrared Emitting Diode in Miniature (T-3/4) Package

Description

CQY36N is a standard GaAs infrared emitting diode in a miniature top view plastic package.

Its flat window provides a wide aperture making it ideal for use with external optics.

The diode is case compatible to the BPW16N phototransistor, allowing the user to assemble his own optical interrupters.



Features

- · Suitable for pulse operation
- Standard T-3/4 flat miniature package
- Wide angle of half intensity $\varphi = \pm 55^{\circ}$
- Peak wavelength $\lambda_p = 950 \text{ nm}$
- · Good spectral matching to Si photodetectors
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

· Radiation source in near infrared range



Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse Voltage		V _R	5	V
Forward current		I _F	100	mA
Surge Forward Current	t _p ≤ 100 μs	I _{FSM}	2	A
Power Dissipation		P _V	170	mW
Junction Temperature		T _j	100	°C
Storage Temperature Range		T _{stg}	- 25 to + 100	°C
Soldering Temperature	t ≤ 3 s	T _{sd}	245	°C
Thermal Resistance Junction/ Ambient		R _{thJA}	450	K/W

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

and	· ·					
Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward Voltage	$I_F = 50 \text{ mA}, t_p \le 20 \text{ ms}$	V_{F}		1.3	1.6	V
Breakdown Voltage	I _R = 100 μA	V _(BR)	5			V
Junction capacitance	$V_{R} = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	C _j		50		pF

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Optical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Radiant Intensity	$I_F = 50 \text{ mA}, t_p \le 20 \text{ ms}$	Ι _e	0.7	1.5	7.5	mW/sr
Radiant Power	$I_F = 50 \text{ mA}, t_p \le 20 \text{ ms}$	φ _e		10		mW
Temp. Coefficient of φ _e	I _F = 50 mA	TKφ _e		- 0.8		%/K
Angle of Half Intensity		φ		± 55		deg
Peak Wavelength	$I_F = 50 \text{ mA}$	λ_{p}		950		nm
Spectral Bandwidth	I _F = 50 mA	Δλ		50		nm
Rise time	$I_F = 1.5 \text{ A}, t_p/T = 0.01, t_p \le 10 \mu\text{s}$	t _r		400		ns
Fall Time	$I_F = 1.5 \text{ A}, t_p/T = 0.01, t_p \le 10 \mu\text{s}$	t _f		450		ns
Virtual Source Diameter		Ø		1.2		mm

Typical Characteristics

 T_{amb} = 25 °C unless otherwise specified

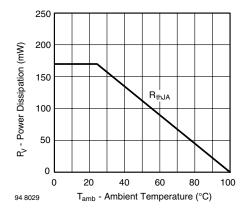


Figure 1. Power Dissipation vs. Ambient Temperature

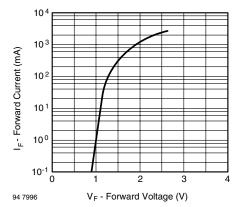


Figure 3. Forward Current vs. Forward Voltage

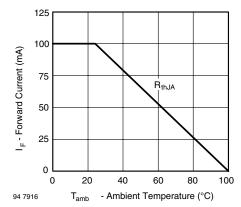


Figure 2. Forward Current vs. Ambient Temperature

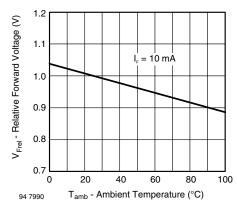


Figure 4. Relative Forward Voltage vs. Ambient Temperature





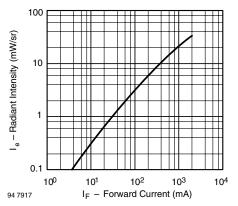


Figure 5. Radiant Intensity vs. Forward Current

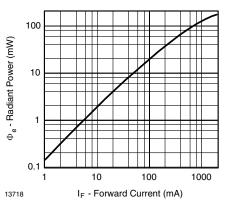


Figure 6. Radiant Power vs. Forward Current

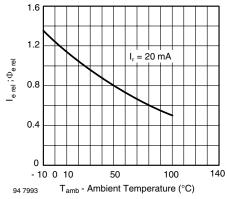


Figure 7. Rel. Radiant Intensity/Power vs. Ambient Temperature

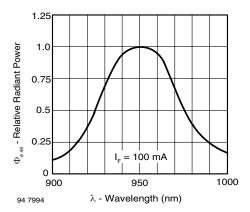


Figure 8. Relative Radiant Power vs. Wavelength

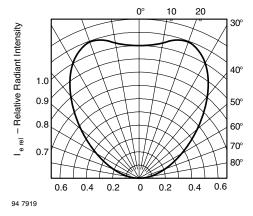
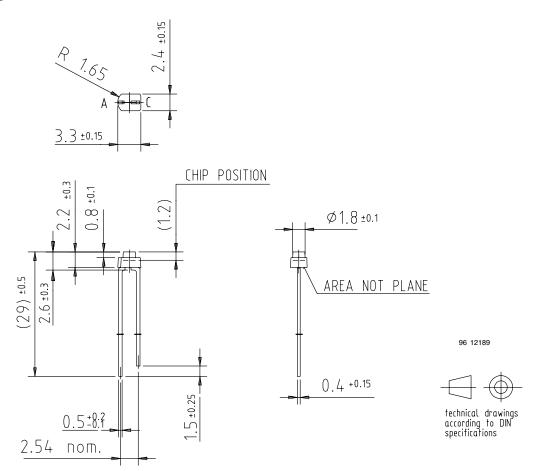


Figure 9. Relative Radiant Intensity vs. Angular Displacement

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Package Dimensions in mm





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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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